## NAND Flash Code Information(1/3)

Last Updated: May 2007

## <u>K 9 X X X X X X X X - X X X X X X X</u> 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18

1. Memory (K)

2. NAND Flash: 9

3. Small Classification

(SLC: Single Level Cell, MLC: Multi Level Cell,

SM: SmartMedia, S/B: Small Block)

1: SLC 1 Chip XD Card

2: SLC 2 Chip XD Card

4: SLC 4 Chip XD Card

5: MLC 1 Chip XD Card

6: MLC 2 Chip XD Card

7: SLC moviNAND

8: MLC moviNAND

A: 3bit MLC MONO

B: 3bit MLC DDP

C: 3bit MLC QDP

D: SLC Dual SM

E: SLC DUAL (S/B)

F: SLC Normal

G: MLC Normal

H: MLC QDP

K: SLC Die Stack

L: MLC DDP

M: MLC DSP

N: SLC DSP

S: SLC Single SM

T: SLC SINGLE (S/B)

U: 2 STACK MSP

W: SLC 4 Die Stack

#### 4~5. Density

12 : 512M	16 : 16M	28 : 128M
32 : 32M	40 : 4M	56 : 256M
64 : 64M	80 : 8M	1G : 1G
2G : 2G	4G : 4G	8G : 8G
AG : 16G	BG: 32G	CG : 64G
DG: 128G	LG : 24G	NG : 96G
ZG : 48G	00 : NONE	

6~7. Organization 00: NONE

08:x8

16: x16

8. Vcc

A: 1.65V~3.6V B: 2.7V (2.5V~2.9V) C: 5.0V (4.5V~5.5V) D: 2.65V (2.4V ~ 2.9V) E: 2.3V~3.6V R: 1.8V (1.65V~1.95V)

Q: 1.8V (1.7V ~ 1.95V) T: 2.4V~3.0V U: 2.7V~3.6V V: 3.3V (3.0V~3.6V)

W: 2.7V~5.5V, 3.0V~5.5V 0: NONE

9. Mode

0: Normal

1: Dual nCE & Dual R/nB

3: Tri /CE & Tri R/B

4: Quad nCE & Single R/nB

5: Quad nCE & Quad R/nB

9:1st block OTP

A: Mask Option 1

L: Low grade

10. Generation

M: 1st Generation

A: 2nd Generation

B: 3rd Generation

C: 4th Generation

D: 5th Generation



# NAND Flash Code Information(2/3)

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11. "--"

12. Package

A : COB C : CHIP BIZ

D: 63-TBGA F: WSOP (Lead-Free)
G: FBGA H: TBGA (Lead-Free)
I: ULGA (Lead-Free) J: FBGA (Lead-Free)

M: TLGA N: TLGA2

P: TSOP1 (Lead-Free) Q: TSOP2 (Lead-Free)

S: TSOP1 (Halogen, Lead-Free)

T : TSOP2 U : COB (MMC) V : WSOP W : Wafer

Y: TSOP1 Z: WELP (Lead-Free)

13. Temp

C : Commercial I : Industrial

S: SmartMedia

B: SmartMedia BLUE

0 : NONE (Containing Wafer, CHIP, BIZ, Exception handling code)

3: Wafer Level 3

#### 14. Bad Block

B: Include Bad Block
D: Daisychain Sample
L: 1~5 Bad Block

N: ini. 0 blk, add. 10 blk S: All Good Block

0 : NONE (Containing Wafer, CHIP, BIZ, Exception handling code)

## 15. Pre-Program Version

0: None

Serial (1~9, A~Z)



# NAND Flash Code Information(3/3)

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## 16. Packing Type

- Common to all products, except of Mask ROM
- Divided into TAPE & REEL(In Mask ROM, divided into TRAY, AMMO Packing Separately)

Divide	Packing Type	New Marking
Component	TAPE & REEL	Т
	Other ( Tray, Tube, Jar )	0 ( Number)
	Stack	S
Module	MODULE TAPE & REEL	Р
	MODULE Other Packing	M

17~18. Customer "Customer List Reference"

